Electrochemical Control of Strong Coupling of CdSe Exciton-Polaritons in Plasmonic Cavities

Nathan G. Sinai*,1, Christian Y. Dones Lassalle*,2, Jennica E. Kelm*,2, Shreya K. Patel1, Sang-Min Park1, Max J.H. Tan1, Teri W. Odom†,1 and Jillian L. Dempsey†,2

*These authors contributed equally to this work.

†Co-corresponding authors

1Department of Chemistry, Northwestern University, Evanston, IL 60208

2Department of Chemistry, University of North Carolina, Chapel Hill, North Carolina 27599-3290, United States

Abstract (129/150 words)

This work reports in-situ (active) electrochemical control over the coupling strength between semiconducting nanoplatelets and a plasmonic cavity. We found that by applying a reductive bias to an Al nanoparticle lattice working electrode, the number of CdSe nanoplatelet emitters that can couple to the cavity is decreased. Strong coupling can be reversibly recovered by discharging the lattice at oxidative potentials relative to the conduction band edge reduction potential of the emitters. By correlating the number of electrons added or removed with the measured coupling strength, we...
identified that loss and recovery of strong coupling is likely hindered by side processes that trap and/or inhibit electrons from populating the nanoplatelet conduction band. These findings demonstrate tunable, external control of strong coupling and offer prospects to tune selectivity in chemical reactions.

**Keywords**: Exciton-polariton, CdSe nanoplatelets, nanoparticle lattice cavity, electrochemical control
TOC

Exciton Bleach

Negative Bias

Strongly Coupled

Weakly Coupled

SLR

HH

LP

H

\( \beta_{\text{HH}} \)

\( \beta_{\text{LP}} \)
Exciton-polaritons are hybrid light-matter quasiparticles that form under strong coupling, which occurs when the coupling between an optical cavity and an exciton exceeds the losses of either.\(^{1-2}\) Exciton-polaritons are important in diverse fields, ranging from quantum computing\(^3\) to sensing\(^4\) to low-threshold lasing.\(^5\) Recently, these quasiparticles have gained attention to control the product distribution of chemical reactions by altering potential energy surfaces.\(^5\) However, most work on polariton-mediated charge transfer,\(^7\) singlet fission,\(^8\) and reaction control\(^9\) has been limited to theory; there are few experiments that have demonstrated exciton-polariton-mediated chemical reactivity.\(^10-11\)

One key parameter to control reactivity is the coupling strength \((g)\) between many \((N)\) emitters and a cavity:\(^{12}\)

\[
g = \sqrt{N} \cdot \mu \cdot \sqrt{\frac{\hbar \omega}{2\varepsilon_0 V_c}}
\]

where \(\mu\) is the transition dipole moment of the emitter, \(\omega\) is the frequency of a photon resonant to the cavity, and \(V_c\) is the mode volume of the cavity. Active tuning (i.e., external, \textit{in-situ} control)\(^{13-14}\) of \(g\) often requires complex means, including varying the refractive index environment through microfluidics\(^{15}\) or raising the temperature of the emitters.\(^{16}\) Ideally, manipulating \(g\) should occur in a simple, non-invasive manner, such that polariton-mediated reactions can be studied without compounding effects. Adjusting the coupling strength by segregating emitters from the cavity is one proposed approach to influence the product distribution of chemical reactions resulting from polariton-altered frontier molecular orbitals of reagents.\(^{17}\)

Populating or depleting frontier molecular orbitals by applying an electrochemical potential is known to change the optical properties of molecular species and therefore exciton formation.\(^{18}\) Similarly, when a negative (positive) potential of appropriate magnitude is applied to semiconducting excitonic materials, electrons (holes) are injected into the conduction (valence) band of the emitters. With the conduction band occupied (or valence band depleted), electronic transitions cannot occur, and optical
absorptions are bleached. As a result, in an ensemble of $N$ semiconductor excitons under reductive bias, fewer emitters are available to couple to the cavity. Although electrical\textsuperscript{19-20} and electrochemical\textsuperscript{21-23} tunability of coupling strength has been realized, the focus has been on either organic dyes or transition metal dichalcogenide (TMD) flake emitters. CdSe nanoplatelets (NPLs) have advantages because of their large oscillator strengths\textsuperscript{24-26} compared to organic emitters and their ease of ligand exchange compared to TMDs\textsuperscript{27-30} and are established materials for strong coupling to a variety of cavities at room temperature.\textsuperscript{31-32} Since CdSe NPLs can be synthesized with a variety of absorption and emission energies based on plate thickness,\textsuperscript{33} they can be used to target a broad range of reaction energetics.

Plasmonic nanoparticle lattices are advantageous cavities for strong coupling and for carrying out chemical reactions due to their open lattice structure.\textsuperscript{34-37} Periodic lattices of metallic nanoparticles can support high-quality surface lattice resonance (SLR) cavity modes by coupling the localized surface plasmons of each nanoparticle to the diffractive photonic modes in the lattice in an index-matched environment.\textsuperscript{38-39} The single substrate and metal nanoparticles of the cavity facilitate incorporation into spectroelectrochemistry experiments, as the cavity is accessible to solvents and reagents, and the lattices can be fabricated on transparent conductive substrates.\textsuperscript{37} By tuning nanoparticle material and shape as well as periodicity, plasmonic lattice cavities can be designed to interact with different excitonic materials.\textsuperscript{39}

Here we show external, \textit{in-situ} control of the coupling strength in polaritons formed between CdSe NPL excitons and a plasmonic lattice cavity. Polariton coupling strength was modulated via an applied electrochemical potential to an Al nanoparticle lattice on an indium tin oxide substrate that functioned as the working electrode. By applying reductive potentials, we incrementally raised the Fermi level of a subset of CdSe NPLs in the film. When the magnitude of that potential exceeded the formal reduction potential of the conduction band edge, the excitonic absorption features of the NPLs bleached. Repeated cycles beyond the conduction band edge were found to suppress the coupling strength
between the cavity and NPLs. Under oxidative applied potentials, the NPL film discharged, and the polariton features were recovered. The extent of the reduction and recovery in coupling strength correlated directly with the number of electrons added or removed from the NPL film, a connection yet to be formalized in the literature. External, in-situ control of the degree of coupling will enable future experiments that take advantage of polariton-mediated reactions.

We designed a custom-built, three-electrode cell for spectroelectrochemical experiments on the coupled lattice cavity–NPL film system (Figure 1a). The transparent working electrode functions as one window, and a second inert window confines the electrolyte solution. The Ag/AgNO₃ reference electrode and Pt wire counter electrode complete the cell and were mounted offset so as not to obstruct the transmission of light through the cell under an applied potential. This architecture allows the electrochemical cell to be mounted into a Fourier transform microscope between a condenser and objective lens⁵,⁴₀ so that changes to polaritons as a result of bias can be quantified in real time (Figure 1b).
Four-monolayer, oleate-capped CdSe NPLs (Figure 1c) were synthesized using our improved procedure and cast into an 110-nm thick film. There are two excitonic transitions in CdSe NPLs: (1) the heavy hole (HH) valence band to the conduction band at 2.41 eV (~514 nm) and (2) the light hole (LH) valence band to the conduction band at 2.58 eV (~480 nm). Photonic cavities consisting of square lattices of Al nanoparticles (diameter $d = 90$ nm, height $h = 60$ nm) with periodicity $a_0 = 320$ nm (Figure 1c).
1d) were fabricated by electron beam lithography on ITO-coated glass slides (Supporting Information). The emitter-cavity system consists of ITO on glass, an Al NP lattice, and a CdSe NPL film (Figure 1e). For electrochemical measurements, samples are immersed in 0.25 M [Bu₄N][PF₆] in CH₃CN electrolyte (Supporting Information) since CH₃CN is a polar solvent with low resistivity and stable in a wide potential window (~ 3 V to –3 V vs. SCE).⁴¹

If the SLR cavity mode is close enough in energy to the heavy or light hole (or both), polaritons can form. Typically, the higher energy eigenmode is referred to as the upper polariton (UP) while the lower energy mode is defined as the lower polariton (LP). Since CdSe NPLs support two excitonic absorptions, depending on the operational frequency of the cavity, a middle polariton (MP) mode can also be present.⁵ Scheme 1 summarizes how an applied bias can inhibit HH and LH excitonic transitions by populating the NPL conduction band with electrons. As a result, the HH and LH hole excitons are suppressed, which lowers the number of available NPLs, N, that can couple to the cavity.

Scheme 1: Fermi and energy level diagrams of the coupled CdSe NPL-Al lattice system with no voltage applied (top) and under a reductive potential (bottom).

The conduction band edge potential of CdSe NPLs was quantified in UV-Vis absorbance spectroelectrochemical experiments of NPL films on Al lattice/ITO substrates (Figure 2). In these
experiments, the applied potential was stepped from –0.94 to –2.34 V vs. Fc+/0. The potential range was selected to ensure that the transition from NPL emitters with unpopulated conduction bands to fully populated was resolved.\textsuperscript{42-46} UV-vis absorbance spectra were collected with large reductive potential steps (100 mV) in the initial 400 mV of the range (from –0.94 to –1.34 V vs. Fc+/0) to minimize exposure of the sample to bias where no change in the absorbance profile was observed. Once bleaching of the LH and HH excitonic features occurred, spectra were collected every 50 mV (from –1.34 to –2.34 V) to track the bleach throughout the population of the conduction band and beyond (Figure 2a). After each reductive step, an oxidative step (–0.14 V vs. Fc+/0) was applied to remove charges from the NPL film (i.e., the NPLs were discharged) and mitigate undesirable charging that may lead to degradation\textsuperscript{47-48} (Supporting Information). We did not observe electrochemical degradation of either the Al lattice or ITO film.
Figure 2: Quantified conduction band edge potentials. (a) Change in absorbance of CdSe NPL film on Al lattice cavity with an increasing applied potential showing the loss of absorbance from the HH and LH exciton transitions. (b) Fitting of the change in absorbance from the HH and LH exciton transitions vs. applied potential with a sigmoid curve to obtain the conduction band edge potential of $-1.67$ V vs. Fc$^{+/0}$. Each reductive and oxidative potential was applied for 35 s.

Figure 2a shows a progressive bleaching of the LH and HH absorption with increasing reductive potentials in the range of $-1.40$ to $-1.85$ V vs. Fc$^{+/0}$. Plots of the change in absorption ($\Delta A$) of both the HH and LH transitions represent the fraction of reduced emitters as a function of applied potential. These data can be fit to a sigmoidal function, as expected from the Nernst equation, and used to determine the formal reduction potential of the conduction band edge ($-1.67 \pm 0.06$ V vs. Fc$^{+/0}$, see Supporting Information). Under such reductive bias, formation of the exciton is inhibited; we use this measured NPL conduction band edge potential as the starting bias to electrochemically tune the coupling in our system.
Figure 3a shows that the HH and LH excitonic transitions of CdSe NPL films are non-dispersive, as expected. By varying the periodicity of the lattice, the Γ-point of SLR bands can be shifted higher or lower in energy. We selected \( a_0 = 320 \text{ nm} \) because this periodicity results in a distinct SLR mode whose Γ-point (\( k_\parallel = 0 \mu \text{m}^{-1}, 2.26 \text{ eV} \)) is lower in energy than the HH, and the most intense SLR bands crossing the HH relatively unobscured (Figure 3b). In order to perform the background correction and normalization required for spectroelectrochemical measurements, we only considered SLR modes excited under transverse electric (TE) polarization. The dispersion diagram of the bare Al nanoparticle lattice shows many modes because of the refractive index mismatch between the \( n = 1.525 \) superstrate and the ITO-glass substrate. Index oil was used for the uncoupled measurements to match the refractive index of glass to minimize the number of unique indices in the system. When the difference in refractive index is high, waveguide modes can form and couple to the SLR and generate waveguide-SLRs (W-SLR). Based on finite-difference time-domain simulations (Supporting Information), we identify the lower energy dispersive X-shaped modes (\( \Gamma \approx 2.26 \text{ eV} \)) as having predominantly dipolar character (SLR1). The higher energy X-shaped mode (\( \Gamma \approx 2.56 \text{ eV} \)) is also predominantly dipolar character (SLR2), however the shift in energy is attributed to the SLR sensitivity to the local refractive index environment of either the ITO or the superstrate. The parabolic mode intersecting SLR1 at \( k_\parallel = 0 \mu \text{m}^{-1} \) has increased field intensity in the ITO layer, and is likely a waveguide mode. For this electrochemical study of polaritons, we will only focus on the cavity mode described by SLR1.
Figure 3c depicts anti-crossing behavior characteristic of strong coupling between the SLR mode of the plasmonic cavity and the HH band of the NPL film at ca. $k_{||} = \pm 2.3 \, \mu m^{-1}$ and 2.42 eV. The LP band occurs below the HH in energy and is overlaid with a teal dashed line based on a fit from the coupled oscillator model. Below ~2.3 eV, the LP retains significant SLR character, matching the transmission from the uncoupled lattice. However, at energies close to the HH, the bands begin to bend outwards, resulting in flat bands at large $k_{||}$ reminiscent of the HH band. The MP, between the 2.42 and 2.58 eV, can likewise be fit and is traced in yellow. Similar to the LP, the MP has a more flat-band shape from the LH at larger $k_{||}$ values. However, the portion of the MP near the HH bends the opposite way, towards $k_{||} = 0 \, \mu m^{-1}$.

Fitting these features is more complicated because of the presence of both SLR$_1$ and SLR$_2$ modes. The UP would fall above the LH in energy out of the frame of the visualized area. By fitting the LP with the coupled oscillator model, we can extract a $g_{HH}$ value that can be compared to the loss values ($\gamma$) of the HH exciton and SLR cavity (Supporting Information). The measurements confirm that the coupling
strength \((g_{HH} \approx 45 \text{ meV})\) is sufficiently large \((\gamma_{ex} = 40 \text{ meV}, \ \gamma_{ca} = 81 \text{ meV})\) to satisfy the criteria for strong coupling \((2g_{HH} > \gamma_{ex}, \ \gamma_{ca})\).

To tune the coupling strength as a function of applied potential, we performed a linear sweep voltammetry experiment, where the applied potential was swept from \(-1.53 \text{ V to } -1.82 \text{ V vs. } \text{Fc}^+/0\). We observed a decrease in coupling at \(-1.74 \text{ V vs. } \text{Fc}^+/0\) (Supporting Information). Informed by the reduction potential of the of the NPL conduction band edge \((-1.67 \text{ V vs. } \text{Fc}^+/0\) and the change in coupling strength at \(-1.74 \text{ V vs. } \text{Fc}^+/0\), a step potential experiment was then performed by alternating between an applied reductive potential \(V_{app} \) of \(-1.78 \text{ V vs. } \text{Fc}^+/0\) and a more positive discharging potential \(V_{dis} \) of \(-0.13 \text{ V vs. } \text{Fc}^+/0\), each for 35 s intervals. Significant charge injection into the NPL conduction band should occur at \(V_{app}\), leading to a bleach of the excitonic absorption features and elimination of strong coupling. Charge can then be removed by applying the “discharge” step to restore strong coupling.

**Figure 4** indicates that the coupling strength can be tuned from strong to the weak coupling under an applied voltage. Without \(V_{app}\), the magnitude of \(g_{HH}\) can be interpreted in the dispersion diagram as the displacement of the LP away from the expected crossing between the SLR and the HH \((k_{||} = \pm 2.3 \text{ \mu m}^{-1})\) (Figure 4a). Through two cycles of \(V_{app}\) and \(V_{dis}\), the coupling strength decreases and recovers. Using our electrochemical cell, we observed that during the second cycle of \(V_{app}\), \(g_{HH}\) contracted by 33% since an estimated 39.5% of NPLs had their excitonic transitions occluded and hence effectively segregated from the cavity (Figure 4b). The obvious band bending of the LP (teal) was reduced, and the LP can no longer be as clearly distinguished from the HH or SLR modes (white), and hence only weak coupling is present.6,53 Through the third and fourth cycles, the band-bending continues to reduce, and the dispersion diagrams of the cavities with and without NPL become more similar. During the 5th cycle of \(V_{app}\), 89% of emitters in the NPL film were bleached, and \(g_{HH}\) decreased significantly, resulting in a significant kink forming between the now nearly completely X-shaped dispersive SLR modes and the flat-banded CdSe film HH (Figure 4c).
Because $g_{HH}$ is directly proportional to $N$, $g_{HH}$ would be expected to stabilize to the same value after each cycle. However, the continual decrease in coupling strength can be rationalized by estimating the number of electrons added and removed from the system. Calculations of the number of electrons in the NPL film during each potential step (Supporting Information) reveals that through the first cycle at $V_{app}$, $1.4 \times 10^{16}$ electrons are added to the system (Figure 5a), resulting in a reduction in $g_{HH}$ of 10 meV (from 45 to 35 meV) (Figure 5b). However, when the system is discharged in that cycle at $-0.13$ V vs. Fc$^{+/0}$ for 35 s, only $4.8 \times 10^{15}$ electrons are removed from the film, and a recovery of 5 meV in $g_{HH}$ was observed. After the first cycle, a net $9.2 \times 10^{15}$ electrons are still in the film, corresponding to 66% of the

**Figure 4**: Repeated voltage and discharge cycles reduce and increase the coupling strength of the system. (a) Dispersion diagrams showing strong coupling before any voltage was applied. Inset is a detail view of the area of anti-crossing, with the heavy hole plotted in white, lower polariton fitting plotted in green, and the location of the original uncoupled SLR (calculated by coupling the Rayleigh anomaly from the empty lattice model with the LSP) in teal. (b) taken during the second cycle of $V_{app}$ = $-1.78$ V vs. Fc$^{+/0}$ applied, and (c) the fifth cycle of $V_{app}$. Each potential was applied for 35 s and was followed by a discharge step of equal duration.
initially added electrons, and $g_{HH}$ has only recovered 50% of the initial deficit by the end of the cycle (Supporting Information). This response is consistent through 5 cycles, after which accurately fitting the LP becomes challenging. The data suggests that strong coupling is not fully recovered at any point with a 35 s discharge step because the number of electrons added to the system are not fully removed within this timescale either.

The incomplete reduction of the film in the first cycle can be explained by the localization of electrochemically injected charge.$^{54-56}$ As electrons are injected into the NPL film, cations from the electrolyte ([Bu$_4$N]$^+$) are also drawn into the film voids.$^{54,56}$ The reduction of NPLs is restricted by the

![Figure 5. Jaynes-Cummings model fitting shows decrease of strong coupling as electrons are added into the system. (a) Plot of number of cumulative number of electrons added to the system ($\times 10^{16}$) after applying a voltage and after discharging for 35 s each. Grey points correspond to the system at the beginning of the experiment prior to applying any potential. Green corresponds to $-1.78$ V vs. Fc$^{+}/0$ applied potential and red points correspond to discharging at $-0.13$ V. (b) Plot of $g_{HH}$ values vs. applied potential or discharge step within each cycle.](image-url)
uptake of charge-compensating ions that depend on the size of the counter ion, the void space of the NPL film, and the length of the NPL ligands.\textsuperscript{54} Therefore, experimental differences in NPL film thickness or packing density can propagate to differences in NPL reduction efficiency. Injected charge can also be trapped in localized states at the NPL surface that will affect conduction band population and limit the full reduction of the NPL film in each cycle within experiment timescales.\textsuperscript{43, 47-48, 57-62} Charge trapping at NPL surface states may also result in chemically irreversible degradation.\textsuperscript{47} The complications of electrochemically injected charge not only affect the addition of electrons, but also the efficient removal of all added electrons in the discharge step.\textsuperscript{43, 58} Additionally, injected charges can react with solvent impurities and prevent injected electrons from reducing the film.\textsuperscript{63-64} Ultimately, we attribute the incomplete removal of electrons and restoration of strong coupling during the cycling experiment to limitations on the rate or amount of charge that can be added or removed.\textsuperscript{56, 65}

In conclusion, we demonstrate that the coupling between CdSe NPLs and a plasmonic lattice cavity can be actively tuned across the strong and weak coupling regimes. The magnitude of the coupling lost and recovered correlated to the number of charges injected or removed from the NPL film. Tracking cumulative charge in an electrochemical system is useful for catalytic processes, helping to determine its efficiency in forming specific products.\textsuperscript{66} For improved recovery, cross-linking or ligand exchange procedures could be used to aid electron and electrolyte movement, and more robust emitters, such as core-shell NPLs, may withstand the harsh reductive environment better than oleate-capped NPLs.\textsuperscript{67} Our open cavity design and thin electrochemical cell show promise for active controlling strong coupling by applying electrochemical potentials. This work provides a foundation to understand the energetics of the upper and lower polariton, which is important for tuning the driving force of polariton-mediated redox reactions. Storing qubits in polaritons, tuning the driving force of photoelectrochemical reactions, and controlling polariton condensates will benefit from continued studies on external, \textit{in-situ} control of coupling strength and polariton energetics.
ASSOCIATED CONTENT

Supporting Information

Lattice and NPL film substrate fabrication, experimental conditions of spectroelectrochemical experiments performed, sigmoidal fit equation parameters for quantification of nanoplatelet conduction band edge potential, FDTD modeling of uncoupled cavity, fitting procedures, spectroelectrochemical linear sweep voltammetry of coupled film and cavity, chronoamperometry of angle-dependent transmission spectroelectrochemical measurements, fitting with the coupled oscillator model and quantification of $g_{\text{HH}}$ as a function of cycled potential (PDF)

Co-Corresponding Author

Jillian L. Dempsey–Department of Chemistry, University of North Carolina at Chapel Hill, Chapel Hill, North Carolina 27599-3290, United States; orcid.org/0000-0002-9459-4166; Email: dempseyj@email.unc.edu

Teri W. Odom – Department of Chemistry, Northwestern University, Evanston, Illinois 60208, United States; Department of Materials Science and Engineering, Northwestern University, Evanston, Illinois 60208, United States; https://orcid.org/0000-0002-8490-292X; Email: todom@northwestern.edu

Authors

Nathan G. Sinai – Department of Chemistry, Northwestern University, Evanston, Illinois 60208, United States; https://orcid.org/0000-0003-3507-992X; Email: NathanSinai2027@u.northwestern.edu

Christian Y. Dones Lassalle–Department of Chemistry, University of North Carolina at Chapel Hill, Chapel Hill, North Carolina 27599-3290, United States; https://orcid.org/0009-0005-0317-457X; Email: chryad@email.unc.edu
Jennica E. Kelm—Department of Chemistry, University of North Carolina at Chapel Hill, Chapel Hill, North Carolina 27599-3290, United States; https://orcid.org/0000-0003-4310-7644; Email: jennica@email.unc.edu

Shreya K. Patel – Department of Chemistry, Northwestern University, Evanston, Illinois 60208, United States; https://orcid.org/0000-0003-0081-7937; Email: shreya.patel2@northwestern.edu

Sang-Min Park – Department of Chemistry, Northwestern University, Evanston, Illinois 60208, United States; https://orcid.org/0000-0002-4306-0375; Email: Sang-minPark2025@u.northwestern.edu

Max J.H. Tan – Department of Chemistry, Northwestern University, Evanston, Illinois 60208, United States; https://orcid.org/0000-0002-6582-0670; Email: jintan2024@u.northwestern.edu

Author Contributions

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